

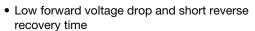
Fast Soft Recovery Rectifier Diode, 10 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	10 A						
V _R	200 V, 400 V, 600 V						
V _F at I _F	1.2 V						
I _{FSM}	130 A						
t _{rr}	50 ns						
T _J max.	150 °C						
Snap factor	0.6						
Package	TO-220AC 2L						
Circuit configuration	Single						

FEATURES

- Glass passivated pellet chip junction
- 150 °C max operating junction temperature





- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF0... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	UNITS							
V _{RRM}		200 to 600	V					
I _{F(AV)}	Sinusoidal waveform	10	А					
I _{FSM}		130						
t _{rr}	1 A, 100 A/µs	50	ns					
V_{F}	10 A, T _J = 25 °C	1.2	V					
T _J		-40 to +150	°C					

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA					
VS-10ETF02-M3	200	300						
VS-10ETF04-M3	400	500	3					
VS-10ETF06-M3	600	700						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	T _C = 128 °C, 180° conduction half sine wave	10					
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied 110		Α				
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	130					
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	se, rated V _{RRM} applied 60					
waximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	85	A ² s				
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied	850	A ² √s				



ELECTRICAL SPECIFICATIONS									
PARAMETER	VALUES	UNITS							
Maximum forward voltage drop	V_{FM}	10 A, T _J = 25 °C		1.2	V				
Forward slope resistance	r _t	T _{.1} = 150 °C		23.5	mΩ				
Threshold voltage	V _{F(TO)}	1) = 150 C		0.85	V				
Maximum reverse leakage current	1	T _J = 25 °C	$V_{B} = Rated V_{RRM}$	0.1	mA				
waxiiiluiii ieveise leakage cuifeiit	IRM	T _J = 150 °C	VR = nateu VRRM	3.0	IIIA				

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	1				
Reverse recovery time	t _{rr}	In at 10 Any	200	ns	I _{FM} t				
Reverse recovery current	I _{rr}	I _F at 10 A _{pk} 25 A/μs	2.75	Α	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				
Reverse recovery charge	Q _{rr}	25 °C	0.32	μC	dir/ Q _{rr}				
Snap factor	S		0.6		I _{RM(REC)}				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS			
Maximum junction and stotemperature range	rage	T _J , T _{Stg}		-40 to +150	°C			
Maximum thermal resistan junction to case	ce	R_{thJC}	DC operation	1.5				
Maximum thermal resistance junction to ambient		R _{thJA}		62	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	R _{thCS} Mounting surface, smooth and greased		1			
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking device	rking device		Case style TO-220AC 2L (JEDEC)	10E	ΓF02 ΓF04 ΓF06			



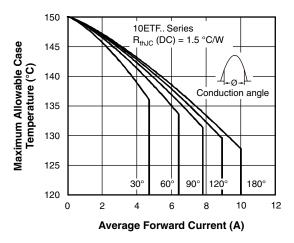


Fig. 1 - Current Rating Characteristics

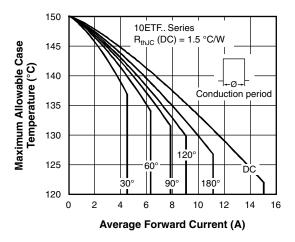


Fig. 2 - Current Rating Characteristics

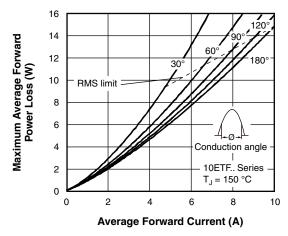


Fig. 3 - Forward Power Loss Characteristics

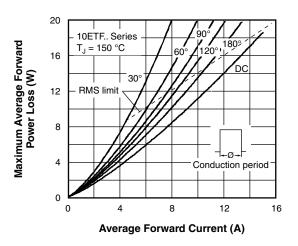


Fig. 4 - Forward Power Loss Characteristics

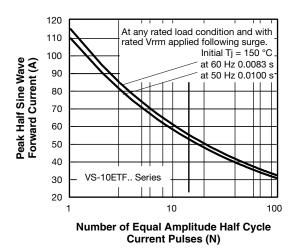


Fig. 5 - Maximum Non-Repetitive Surge Current

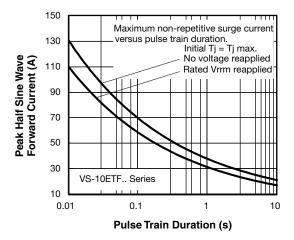


Fig. 6 - Maximum Non-Repetitive Surge Current

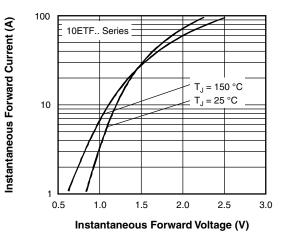
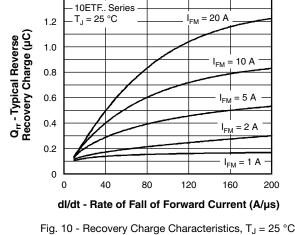


Fig. 7 - Forward Voltage Drop Characteristics



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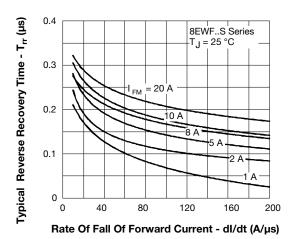


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C

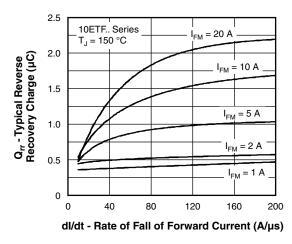


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

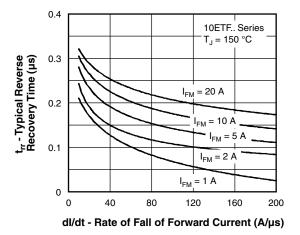
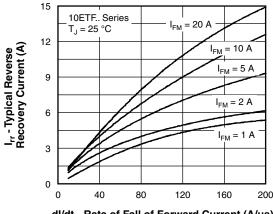


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

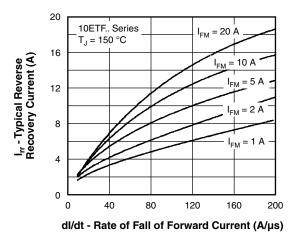


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

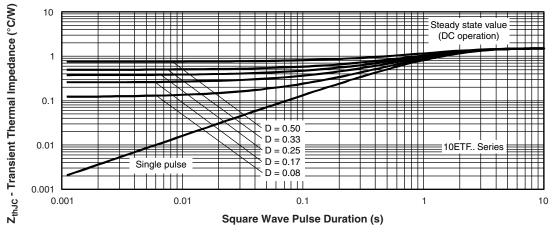
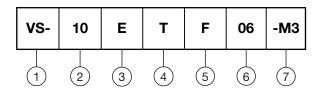


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (10 = 10 A)

3 - Circuit configuration:

E = single

4 - Package:

T = 2L TO-220AC

5 - Type of silicon:

F = fast soft recovery rectifier

02 = 200 V04 = 400 V

Voltage code x 100 = V_{RRM}

06 = 600 V

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-10ETF02-M3	50	Antistatic plastic tube					
VS-10ETF04-M3	50	Antistatic plastic tube					
VS-10ETF06-M3	50	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96156</u>						
Part marking information	www.vishay.com/doc?95391					



TO-220AC 2L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES S	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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